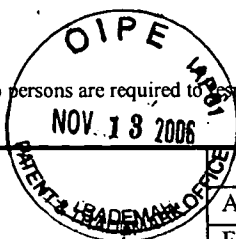


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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Complete if Known

Application Number	10/572,655
Filing Date	March 20, 2006
First Named Inventor	Dominik EISERT
Art Unit	-- 2811
Examiner Name	Cathy N. Lam
Attorney Docket Number	5367-223PUS

Sheet 1 of 3

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind-Code ² (if known)			
/C.L./		US-2003/0127654 A1	07/10/2003	Eisert et al.	
		US-6,649,939 B1	11/18/2003	Wirth	
		US-6,111,272	08/29/2000	Heinen	
		US-6,229,160 B1	05/08/2001	Krames et al.	
		US-6,258,618 B1	07/10/2001	Lester	
		US-6,091,085	07/18/2000	Lester	
		US-2006/0097271 A1	05/11/2006	Eisert et al.	
		US-6,410,942 B1	06/25/2002	Thibeault et al.	
		US-6,346,771 B1	02/12/2002	Salam	
		US-6,878,563 B2	04/12/2005	Bader et al.	
		US-2004/0046179 A1	03/11/2004	Baur et al.	
		US-2004/0026709 A1	02/12/2004	Bader et al.	
		US-2004/0033638 A1	02/19/2004	Bader et al.	
		US-5,633,527	05/27/1997	Lear	
		US-6,730,939 B2	05/04/2004	Eisert et al.	
		US-6,445,010 B1	09/03/2002	Ebeling	
		US-5,200,668	04/06/1993	Ohashi et al.	

Examiner
Signature

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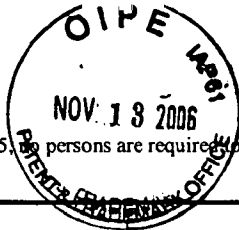
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		First Named Inventor	Dominik EISERT
		Art Unit	-- 2811
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Sheet 2 of 3	Attorney Docket Number	5367-223PUS	

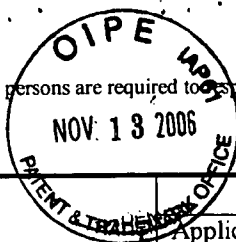
FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Country Code ² Number ⁴ Kind-Code ⁵ (if known)				
/C.L./		WO 02/41406 A1	05/23/2002	Eliashevich et al.		
		JP 2001-168387	06/22/2001	Shibata et al.		See English Abstract
		WO 01/61765 A1	08/23/2001	Eisert et al.		
		JP 2000-196152	07/14/2000	Okazaki et al.		See English Abstract
		EP 1 263 058 A2	05/29/2002	Suehiro et al.		
		DE 199 43 406 A1	04/12/2001	Wirth		
		EP 0 905 797 A2	08/27/1998	Heinen		
		DE 199 11 717 A1	09/28/2000	Späth et al.		See English Abstract
		DE 198 07 758 A1	12/10/1998	Krames et al.		
		JP 08-288543 A	11/01/1996	Takahashi		See English Abstract
		WO 01/41225 A2	06/07/2001	Thibeault et al.		
		DE 100 26 255 A1	11/08/2001	Mundbrod et al.		
		DE 101 11 501 A1	09/19/2002	Baur et al.		
		DE 100 51 465 A1	05/02/2002	Hahn et al.		
		WO 99/14797	03/25/1999	Lo		
		WO 96/37000	11/21/1996	Heinen		See English Abstract
		WO 96/26550	08/29/1996	Fischer et al.		See English Abstract
		WO 00/60648	10/12/2000	Heinen		See English Abstract
		WO 90/05998	05/31/1990	Ohashi et al.		
		DE 100 06 738 A1	09/13/2001	Eisert et al.		

Examiner Signature	/Cathy Lam/	Date Considered	09/30/2008
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		Filing Date	March 20, 2006
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		Examiner Name	Cathy N. Lam
Sheet 3 of 3	Attorney Docket Number	5367-223PUS	

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
/C.L./		J. Cao et al., "Improved quality GaN by growth on compliant silicon-on-insulator substrates using metalorganic chemical vapor deposition", Journal of Applied Physics, Vol. 83, No. 7, pp. 3829-3834, April 1, 1998	
		R. Windisch et al., "High-Efficiency Surface-Textured LEDs", Compound Semiconductor, Vol. 6, No. 4, pp. 55-58, May/June 2000	
		Y.K. Song et al., "Resonant-cavity InGaN quantum-well blue light-emitting diodes", Applied Physics Letters, Vol. 77, No. 12, pp. 1744-1746, September 18, 2000	
		A.J. Steckl et al., "Growth and Characterization of GaN Thin Films on SiC SOI Substrates", Journal of Electronics Materials, Vol. 26, No. 3, pp. 217-223, 1997	
		W.S. Wong et al., "Integration of GaN Thin Films with Dissimilar Substrate Materials by Pd-In Metal Bonding and Laser Lift-Off", Journal of Electronic Materials, Vol. 28, No. 12, pp. 1409-1413, 1999	
		I. Schnitzer et al., "30%, external quantum efficiency from surface textured, thin-film light-emitting diodes", Applied Physics Letter, Vol. 63, No. 18, pp. 2174-2176, October 18, 1993	

Examiner Signature	/Cathy Lam/	Date Considered	09/30/2008
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